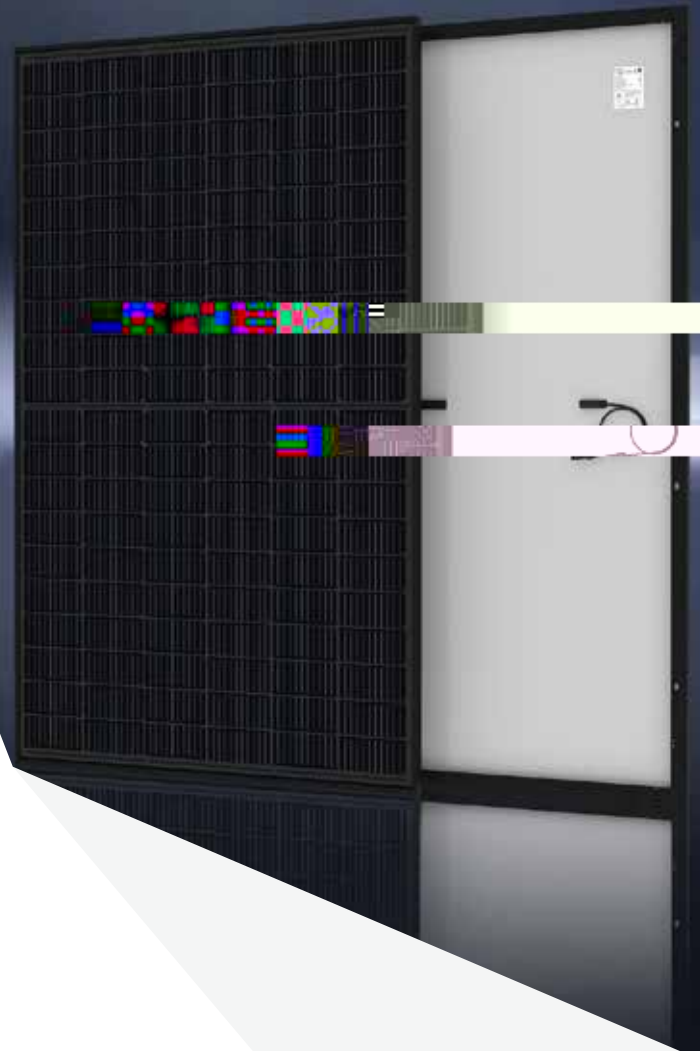


BISTAR



10BB Half-cut Cell Technology

New circuit design, lower internal current, lower R_s loss
Ga doped wafer, attenuation <2% (1st year) / 0.55% (Linear)



Significantly Lower the Risk of Hot Spot

Special circuit design with much lower hot spot temperature



Lower LCOE

2% more power generation, lower LCOE



Excellent Anti-PID Performance

2 times of industry standard Anti-PID test



IP68 Junction Box

High waterproof level



12 Years
Quality
Assurance

2 Years
Power Output
Guarantee

Linear Performance Warranty

